

Search History. (12 pp.) ~~4~~... (3/25/5)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	6	"753524".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/26 06:05
S2	1	S1 and grain adj boundar\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 14:09
S3	17	((("5,170,244") or ("5,250,931") or ("5,525,822") or ("5,744,824") or ("5,780,872") or ("5,796,150") or ("5,821,138") or ("5,818,070") or ("5,821,622") or ("5,859,443") or ("5,864,150") or ("5,929,464") or ("5,942,768") or ("6,147,667") or ("6,211,536") or ("6,380,560") or ("20010018224")).PN.	US-PGPUB; USPAT	OR	OFF	2005/03/14 14:09
S4	33	((("5,170,244") or ("5,250,931") or ("5,525,822") or ("5,744,824") or ("5,780,872") or ("5,796,150") or ("5,821,138") or ("5,818,070") or ("5,821,622") or ("5,859,443") or ("5,864,150") or ("5,929,464") or ("5,942,768") or ("6,147,667") or ("6,211,536") or ("6,380,560") or ("20010018224")).PN.	US-PGPUB; USPAT; DERWENT	OR	OFF	2005/03/14 14:16
S5	10	CN-1118521\$-\$\$.did. JP-07135318\$-\$\$.did. JP-08078329\$-\$\$.did. JP-08213634\$-\$\$.did. JP-08288522\$-\$\$.did. JP-09022077\$-\$\$.did.	EPO; JPO; DERWENT	OR	OFF	2005/03/14 14:22
S6	4	JP-09312260\$-\$\$.did. JP-10270363\$-\$\$.did.	EPO; JPO; DERWENT	OR	OFF	2005/03/14 14:24
S7	44	S4 S5 S6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 14:24
S8	3	("6380560").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 15:28

S9	24	((("5170244") or ("5250931") or ("5525822") or ("5780872") or ("5796150") or ("5818070") or ("5821138") or ("5821622") or ("5859443") or ("5864150") or ("5929464") or ("6147667"))).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 14:47
S10	719	grain adj boundar\$3 near6 (channel active) and (thin adj film adj transistor tft)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 15:32
S11	488	grain adj boundar\$3 near6 (channel active) and (thin adj film adj transistor tft) and "257"/\$8.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 15:33
S12	27	lattice near10 grain adj boundar\$3 near6 (channel active) and (thin adj film adj transistor tft) and "257"/\$8.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 15:33
S13	3	void near10 grain adj boundar\$3 and tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 16:01
S14	11	lattice adj defect near10 grain adj boundar\$3 and tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 16:01
S15	47	(high adj resolution adj tem hrtem high adj resolution adj2 electron adj microscopy) and grain adj boundar\$3 and (semiconductor near2 thin adj film tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 07:10
S16	33	(high adj resolution adj tem hrtem high adj resolution adj2 electron adj microscopy) and ((trap void) near6 (grain adj boundar\$3)) and (semiconductor near2 thin adj film tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 07:11
S17	155	(tem hrtem electron adj microscopy) and ((trap void) near6 (grain adj boundar\$3)) and (semiconductor near2 thin adj film tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 07:12

S18	0	dangling adj bond near10 grain adj boundar\$3 and hydrogenated near3 (silicon si polysilicon) and (high adj resolution adj transmission adj electron adj microscopy)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:11
S19	0	dangling adj bond near10 grain adj boundar\$3 and (high adj resolution adj transmission adj electron adj microscopy)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:11
S20	36	dangling adj bond and (high adj resolution adj transmission adj electron adj microscopy)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:11
S21	36	dangling adj bond and (high adj resolution adj transmission adj electron adj microscopy) and (silicon polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:11
S22	49	dangling adj bond and (high adj resolution adj transmission adj electron adj microscopy hrtem) and (silicon polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:45
S25	10	personal adj computer near10 (tft thin adj film adj transistor).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:56
S26	1763	personal adj computer.ti,ab,clm. and (tft thin adj film adj transistor).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:57
S27	911	personal adj computer.ti,ab,clm. and (tft thin adj film adj transistor).ti,ab,clm. and liquid adj crystal adj display.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:58
S28	207	personal adj computer.ti. and (tft thin adj film adj transistor).ti,ab, clm. and liquid adj crystal adj display.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:58
S29	164	personal adj computer.ti. and (tft thin adj film adj transistor).ab. and liquid adj crystal adj display.ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:04

S30	2	JP-08179306\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:25
S31	121	personal adj computer.ti. and (liquid adj crystal adj display lcd) near10 (thin adj film adj transistor tft)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:26
S32	119	S31 not yamazaki.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:40
S33	2	JP-08211367\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:49
S34	2	"5854627".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:55
S35	9114	(thin adj film adj transistor tft) and silicon and pixel adj electrode and (liquid adj crystal adj display lcd)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:57
S36	188	(thin adj film adj transistor tft) and silicon and pixel adj electrode and (liquid adj crystal adj display lcd) and grain near3 orientation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:58
S37	8	(thin adj film adj transistor tft) and silicon and pixel adj electrode and (liquid adj crystal adj display lcd) and grain near3 orientation near6 channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 09:58

S38	82	(US-20010018224-\$ or US-20020030190-\$ or US-20020040981-\$ or US-20020043682-\$ or US-20020070406-\$ or US-20020079484-\$ or US-20030001832-\$ or US-20030107077-\$ or US-20030211669-\$ or US-20040031986-\$ or US-20040080481-\$ or US-20040094765-\$ or US-20040164300-\$ or US-20040222424-\$).did. or (US-4352834-\$ or US-4392452-\$ or US-5170244-\$ or US-5250931-\$ or US-5525822-\$ or US-5744824-\$ or US-5780872-\$ or US-5796150-\$ or US-5818070-\$ or US-5821138-\$ or US-5821622-\$ or US-5859443-\$ or US-5864150-\$ or US-5929464-\$ or US-5942768-\$ or US-6147667-\$ or US-6211536-\$ or US-6303963-\$ or US-6323515-\$ or US-6335716-\$ or US-6380560-\$ or US-6462723-\$ or US-6472684-\$ or US-6509602-\$ or US-6597014-\$ or US-6597034-\$).did. or (US-6603453-\$ or US-6605497-\$ or US-6667494-\$ or US-6670635-\$ or US-6717179-\$ or US-6756640-\$ or US-6831727-\$ or US-6093243-\$ or US-6066872-\$ or US-5879447-\$ or US-5712496-\$ or US-5582640-\$ or US-5854627-\$).did. or (JP-08078329-\$ or JP-08213634-\$ or JP-08288522-\$ or JP-09022077-\$ or JP-09312260-\$ or JP-10270363-\$ or JP-08211367-\$).did. or (EP-236629-\$ or EP-342925-\$ or EP-686308-\$ or JP-06317814-\$ or JP-07135318-\$ or JP-08006053-\$ or JP-08023100-\$ or JP-08078329-\$ or JP-08204207-\$ or JP-08213634-\$ or JP-08288522-\$ or JP-09022077-\$ or JP-09102613-\$ or JP-09312260-\$ or US-5796150-\$ or JP-10197897-\$ or JP-10209465-\$ or JP-10270363-\$ or JP-10303129-\$ or US-5859443-\$ or US-5864150-\$ or JP-08179306-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2005/03/15 12:18
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S39	24	S38 and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 12:24
S40	41	S38 and capacitance	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 12:26
S41	18	S38 and auxiliary adj (capacitance capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 12:35
S42	271	auxiliary adj (capacitance capacitor) near6 (LCD liquid adj crystal adj display)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 12:35
S43	195	auxiliary adj (capacitance capacitor) near6 (LCD liquid adj crystal adj display) and (tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 12:36
S44	136	auxiliary adj (capacitance capacitor) near4 (LCD liquid adj crystal adj display) and (tft thin adj film adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 12:58
S45	13	channel near3 length and S38	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:08
S46	2413	channel near3 length and (tft thin adj film adj transistor).ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:09
S47	640	channel adj length.ti,ab,clm. and (tft thin adj film adj transistor).ti, ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:09
S48	19	channel adj length.ti,ab,clm. and (tft thin adj film adj transistor).ti, ab,clm. and channel near4 length near4 ("mum." micron)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:12

S49	11	channel adj length.ti,ab,clm. and (tft thin adj film adj transistor).ti, ab,clm. and channel near4 length near4 ("mum." micron) and (liquid adj crystal adj display LCD)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:13
S50	6	"107113".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:03
S51	2005	257/66	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:03
S52	2420	257/72	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:03
S53	2853	257/59	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:03
S54	631	257/290	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:03
S55	1029	257/291	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:03
S56	998	257/292	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:04
S57	6444	S51 S52 S53 S54 S55 S56	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:04
S58	1479	345/92	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:08

S59	6450	S57 S58 and personal adj computer and (thin adj film adj transistor tft) and (liquid adj crystal adj display lcd) and grain adj (boundary boundaries) and (void dangling adj bond trap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:10
S60	91	(S57 S58) and personal adj computer and (thin adj film adj transistor tft) and (liquid adj crystal adj display lcd) and grain adj (boundary boundaries) and (void dangling adj bond trap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 14:11
S61	44	(US-20010018224-\$).did. or (US-6211536-\$ or US-6380560-\$ or US-5864150-\$ or US-6147667-\$ or US-5942768-\$ or US-5929464-\$ or US-5859443-\$ or US-5821622-\$ or US-5821138-\$ or US-5744824-\$ or US-5818070-\$ or US-5796150-\$ or US-5780872-\$ or US-5525822-\$ or US-5250931-\$ or US-5170244-\$).did. or (JP-08288522-\$ or JP-08213634-\$ or JP-09022077-\$ or JP-08078329-\$ or JP-09312260-\$ or JP-10270363-\$).did. or (US-5864150-\$ or US-5859443-\$ or JP-10303129-\$ or US-5796150-\$ or JP-10209465-\$ or JP-10197897-\$ or JP-08213634-\$ or JP-09102613-\$ or JP-08288522-\$ or JP-08023100-\$ or JP-08204207-\$ or JP-06317814-\$ or JP-08006053-\$ or EP-342925-\$ or EP-686308-\$ or EP-236629-\$ or JP-09022077-\$ or JP-08078329-\$ or JP-10270363-\$ or JP-07135318-\$ or JP-09312260-\$).did.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2005/03/15 14:25
S62	6	"107113".ap.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2005/03/15 14:26
S63	372	easthom.xp.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/16 06:34
S64	6	"496953".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/16 06:39

S65	11	S63 and chip adj resistor.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/16 06:44
S66	6	"107113".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/16 14:49

S68	4	S67 and okada.in.	US-PGPUB; USPAT; JPO; DERWENT	OR	OFF	2005/03/17 14:29
S69	3	"6730932".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/26 06:18
S70	491	pixel adj matrix adj circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/26 06:19
S71	460058	(liquid adj crystal adj display LCD liquid adj crystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/26 06:19
S72	11	S70 not S71	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/26 06:20
S73	11	S72 not "349"/\$7.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/26 06:36
S74	520	liquid adj crystal adj display near4 pixel adj electrode and personal adj computer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/26 06:38
S75	189	liquid adj crystal adj display near4 pixel adj electrode.ti,ab,clm. and personal adj computer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/26 06:38
S76	42	liquid adj crystal adj display near4 pixel adj electrode.ti,ab,clm. and personal adj computer.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/26 06:48
S77	3	"6380560".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/26 06:45

S78	2	"5582640".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/26 06:49
S79	2	jp-08211367\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/26 06:56
S80	2	jp-06230422\$-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/26 06:56